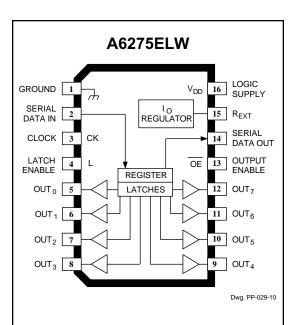
6275

8-BIT SERIAL-INPUT, CONSTANT-CURRENT LATCHED LED DRIVER



Note that the A6275EA (DIP) and the A6275ELW (SOIC) are electrically identical and share a common terminal number assignment.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DD}
Output Voltage Range,
V _O 0.5 V to +17 V
Output Current, I _O 90 mA
Ground Current, I _{GND} 750 mA
Input Voltage Range,
$V_{\rm I}$ -0.4 V to V_{DD} + 0.4 V
Package Power Dissipation,
P _D See Graph
Operating Temperature Range,
$T_{\rm A}$
Storage Temperature Range,
T_S 55°C to +150°C
Caution: These CMOS devices have input static protection (Class 2) but are still suscep-

Caution: These CMOS devices have input static protection (Class 2) but are still susceptible to damage if exposed to extremely high static electrical charges. The A6275EA and A6275ELW are specifically designed for LEDdisplay applications. Each BiCMOS device includes an 8-bit CMOS shift register, accompanying data latches, and eight npn constantcurrent sink drivers. Except for package style and allowable package power dissipation, the two devices are identical.

The CMOS shift register and latches allow direct interfacing with microprocessor-based systems. With a 5 V logic supply, typical serial data-input rates are up to 20 MHz. The LED drive current is determined by the user's selection of a single resistor. A CMOS serial data output permits cascade connections in applications requiring additional drive lines. For inter-digit blanking, all output drivers can be disabled with an ENABLE input high. Similar 150 mA output devices are available as the A6277EA and A6277ELW; similar 16-bit devices are available as the A6276EA and A6276ELW.

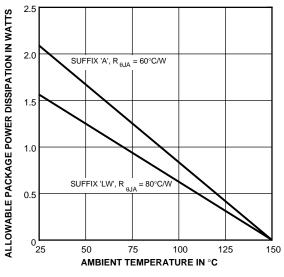
Two package styles are provided for through-hole DIP (suffix A) or surface-mount SOIC (suffix LW). Under normal applications, copper lead frames and low logic-power dissipation allow these devices to sink maximum rated current through all outputs continuously over the operating temperature range (90 mA, 0.9 V drop, $+85^{\circ}$ C). Both devices are also available for operation over the standard temperature range of -20°C to +85°C. To order, change the suffix letter 'E' to 'S'.

FEATURES

- To 90 mA Constant-Current Outputs
- Under-Voltage Lockout
- Low-Power CMOS Logic and Latches
- High Data Input Rate
- Pin-Compatible with TB62705CP

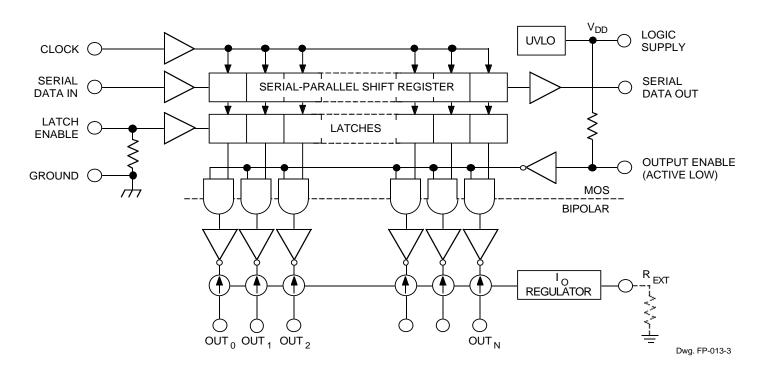
Always order by complete part number, e.g., A6275EA.





Dwg. GP-018B

FUNCTIONAL BLOCK DIAGRAM



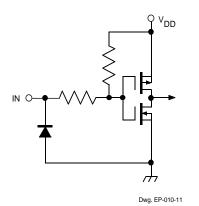


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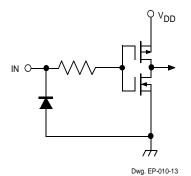
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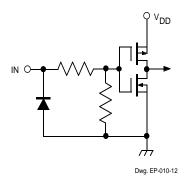




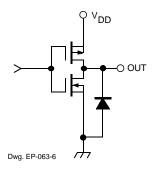




CLOCK and SERIAL DATA IN



LATCH ENABLE



SERIAL DATA OUT

TRUTH TABLE

Serial	Clock	Shift Register Contents			Serial Latch	Latch Contents						Output	Output Contents			
Data Input			I ₂	l ₃	 I _{N-1}	I _N	Data Output	Enable Input	I ₁	l ₂	l ₃		I _{N-1}	I _N	Enable Input	I ₁ I ₂ I ₃ I _{N-1} I _N
Н	Г	н	R ₁	R ₂	 R _{N-2}	R _{N-1}	R _{N-1}									
L	Ч	L	R ₁	R_2	 R _{N-2}	R _{N-1}	R _{N-1}									
х	l	R ₁	R_2	R ₃	 R _{N-1}	R _N	R _N									
		х	Х	Х	 Х	х	x	L	R ₁	R_2	R_3		R _{N-1}	R_N		
		Р ₁	P ₂	Ρ3	 P _{N-1}	P _N	P _N	Н	P ₁	P ₂	P ₃		P _{N-1}	P _N	L	P ₁ P ₂ P ₃ P _{N-1} P _N
									Х	Х	Х		Х	Х	н	ннн…н н

ELECTRICAL CHARACTERISTICS at T_A = +25°C, V_{DD} = 5 V (unless otherwise noted).

				Lim	its	
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Supply Voltage Range	V _{DD}	Operating	4.5	5.0	5.5	V
Under-Voltage Lockout	V _{DD(UV)}	V_{DD} = 0 \rightarrow 5 V	3.4	_	4.0	V
Output Current	Ι _ο	V_{CE} = 0.7 V, R_{EXT} = 250 Ω	64.2	75.5	86.8	mA
(any single output)		V_{CE} = 0.7 V, R_{EXT} = 470 Ω	34.1	40.0	45.9	mA
Output Current Matching	Δl _O	0.4 V \leq V _{CE(A)} = V _{CE(B)} \leq 0.7 V:				
(difference between any		R _{EXT} = 250 Ω	-	±1.5	±6.0	%
two outputs at same V_{CE})		R _{EXT} = 470 Ω	_	±1.5	±6.0	%
Output Leakage Current	I _{CEX}	V _{OH} = 15 V	_	1.0	5.0	μA
Logic Input Voltage	V _{IH}		0.7V _{DD}	_	V_{DD}	V
	V _{IL}		GND	_	$0.3V_{DD}$	V
SERIAL DATA OUT	V _{OL}	I _{OL} = 500 μA	_	_	0.4	V
Voltage	V _{OH}	I _{OH} = -500 μA	4.6	_	_	V
Input Resistance	R _I	ENABLE Input, Pull Up	150	300	600	kΩ
		LATCH Input, Pull Down	100	200	400	kΩ
Supply Current	I _{DD(OFF)}	R _{EXT} = open, V _{OE} = 5 V	_	0.8	1.4	mA
		R_{EXT} = 470 Ω , V_{OE} = 5 V	3.5	6.0	8.0	mA
		R_{EXT} = 250 Ω , V_{OE} = 5 V	6.5	11	15	mA
	I _{DD(ON)}	R_{EXT} = 470 Ω , V_{OE} = 0 V	5.0	10	14	mA
		R _{EXT} = 250 Ω, V _{OE} = 0 V	8.0	16	24	mA

Typical Data is at $V_{DD} = 5$ V and is for design information only.

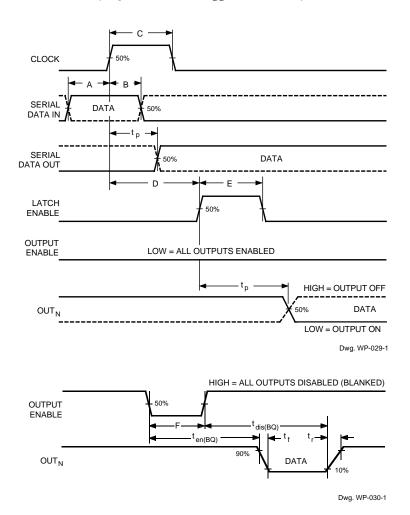


SWITCHING CHARACTERISTICS at T_A = 25°C, V_{DD} = V_{IH} = 5 V, V_{CE} = 0.4 V, V_{IL} = 0 V, R_{EXT} = 470 Ω , I₀ = 40 mA, V_L = 3 V, R_L = 65 Ω , C_L = 10.5 pF.

				Li	imits	
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Propagation Delay Time	t _{pHL}	CLOCK-OUT _n	_	350	1000	ns
		LATCH-OUT _n	_	350	1000	ns
		ENABLE-OUT _n	_	350	1000	ns
		CLOCK-SERIAL DATA OUT	_	40	_	ns
Propagation Delay Time	t _{pLH}	CLOCK-OUT _n	_	300	1000	ns
		LATCH-OUT _n	_	300	1000	ns
		ENABLE-OUT _n	_	300	1000	ns
		CLOCK-SERIAL DATA OUT	_	40	_	ns
Output Fall Time	t _f	90% to 10% voltage	150	350	1000	ns
Output Rise Time	t _r	10% to 90% voltage	150	300	600	ns

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	V _{DD}		4.5	5.0	5.5	V
Output Voltage	Vo		_	1.0	4.0	V
Output Current	I _O	Continuous, any one output	_	_	90	mA
	I _{ОН}	SERIAL DATA OUT	_	_	-1.0	mA
	I _{OL}	SERIAL DATA OUT	_	_	1.0	mA
Logic Input Voltage	V _{IH}		$0.7V_{DD}$	_	V _{DD} + 0.3	V
	V _{IL}		-0.3	_	0.3V _{DD}	V
Clock Frequency	f _{CK}	Cascade operation	_	_	10	MHz



TIMING REQUIREMENTS and SPECIFICATIONS

(Logic Levels are V_{DD} and Ground)

A. Data Active Time Before Clock Pulse	
(Data Set-Up Time), t _{su(D)}	60 ns
B. Data Active Time After Clock Pulse	
(Data Hold Time), t _{h(D)}	20 ns
C. Clock Pulse Width, t _{w(CK)}	50 ns
D. Time Between Clock Activation	
and Latch Enable, t _{su(L)}	. 100 ns
E. Latch Enable Pulse Width, $t_{w(L)}$. 100 ns
F. Output Enable Pulse Width, $t_{w(OE)}$	4.5 µs
NOTE – Timing is representative of a 10 MHz clock.	
Significantly higher speeds are attainable.	
— Max. Clock Transition Time, t_r or t_f	10 µs

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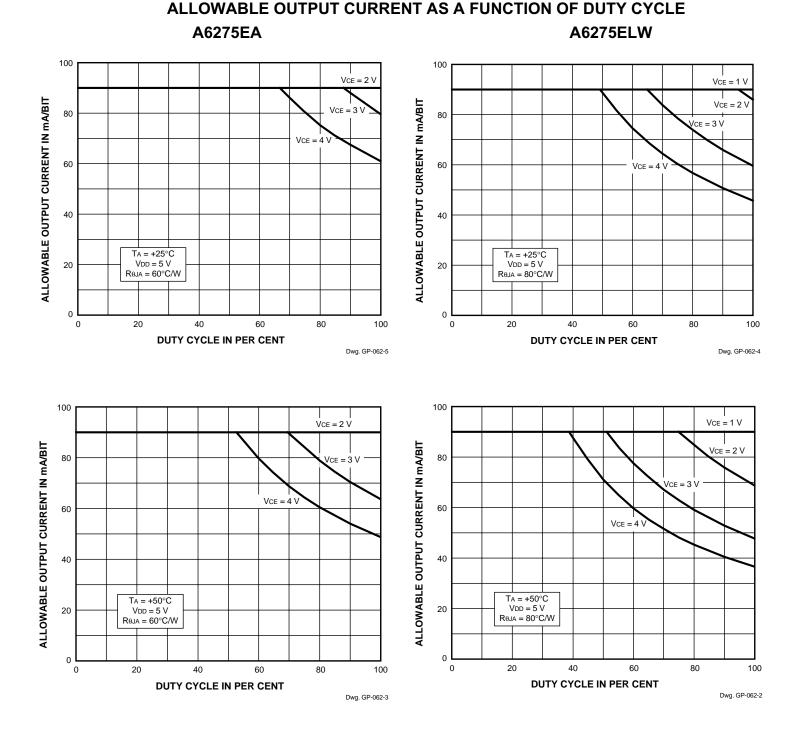
Information present at any register is transferred to the respective latch when the LATCH ENABLE is high (serial-toparallel conversion). The latches will continue to accept new data as long as the LATCH ENABLE is held high. Applications where the latches are bypassed (LATCH ENABLE tied high) will require that the OUTPUT ENABLE input be high during serial data entry.

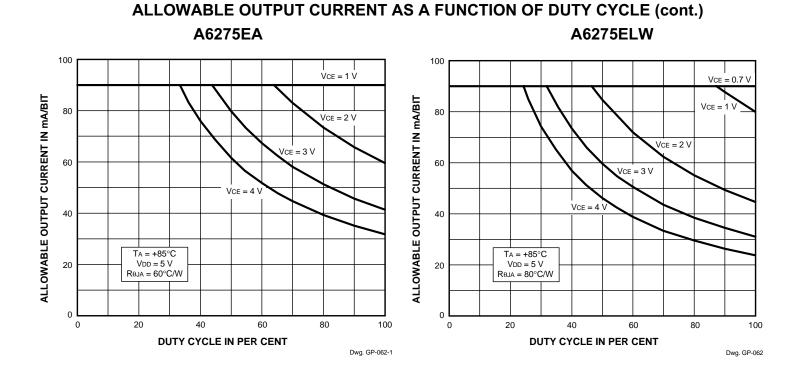
When the OUTPUT ENABLE input is high, the output source drivers are disabled (OFF). The information stored in the latches is not affected by the OUTPUT ENABLE input. With the OUTPUT ENABLE input low, the outputs are controlled by the state of their respective latches.



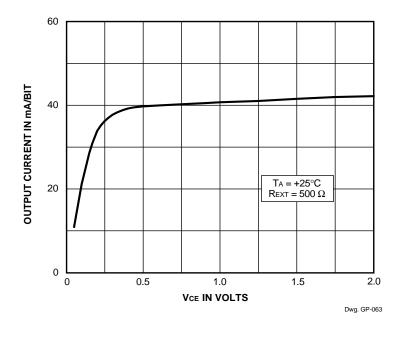
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TYPICAL CHARACTERISTICS





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TERMINAL DESCRIPTION

Terminal No.	Terminal Name	Function
1	GND	Reference terminal for control logic.
2	SERIAL DATA IN	Serial-data input to the shift-register.
3	CLOCK	Clock input terminal for data shift on rising edge.
4	LATCH ENABLE	Data strobe input terminal; serial data is latched with high-level input.
5-12	OUT ₀₋₇	The eight current-sinking output terminals.
13	OUTPUT ENABLE	When (active) low, the output drivers are enabled; when high, all output drivers are turned OFF (blanked).
14	SERIAL DATA OUT	CMOS serial-data output to the following shift-register.
15	R _{EXT}	An external resistor at this terminal establishes the output current for all sink drivers.
16	SUPPLY	(V _{DD}) The logic supply voltage (typically 5 V).

The products described here are manufactured under one or more U.S. patents or U.S. patents pending.

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 (R_{EXT}) as shown in the figure below.

100 Vce = 0.7 V 80 **OUTPUT CURRENT IN mA/BIT** 60 40 20 0 **-**100 200 700 2 k 3 k 300 500 1 k CURRENT-CONTROL RESISTANCE, R EXT IN OHMS Dwg. GP-061

The load current per bit (I_0) is set by the external resistor

Package Power Dissipation (P_D). The maximum allowable package power dissipation is determined as $P_D(max) = (150 - T_A)/R_{\theta JA}$. The actual package power dissipation is $P_D(act) = dc(V_{CE} \bullet I_O \bullet 8) + (V_{DD} \bullet I_{DD})$.

When the load supply voltage is greater than 3 V to 5 V, considering the package power dissipating limits of these devices, or if $P_D(act) > P_D(max)$, an external voltage reducer (V_{DROP}) should be used.

Load Supply Voltage (V_{LED}). These devices are designed to operate with driver voltage drops (V_{CE}) of 0.4 V to 0.7 V with LED forward voltages (V_F) of 1.2 V to 4.0 V. If higher voltages are dropped across the driver, package power dissipation will be increased significantly. To minimize package power dissipation, it is recommended to use the lowest possible load supply voltage or to set any series dropping voltage (V_{DROP}) as

 $V_{DROP} = V_{LED} - V_F - V_{CE}$ with $V_{DROP} = I_o \bullet R_{DROP}$ for a single driver, or a Zener diode (V_Z), or a series string of diodes (approximately



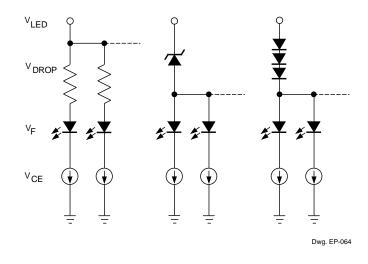


0.7 V per diode) for a group of drivers. If the available voltage source will cause unacceptable dissipation and series resistors or diode(s) are undesirable, a regulator such as the Sanken Series SAI or Series SI can be used to provide supply voltages as low as 3.3 V.

For reference, typical LED forward voltages are:

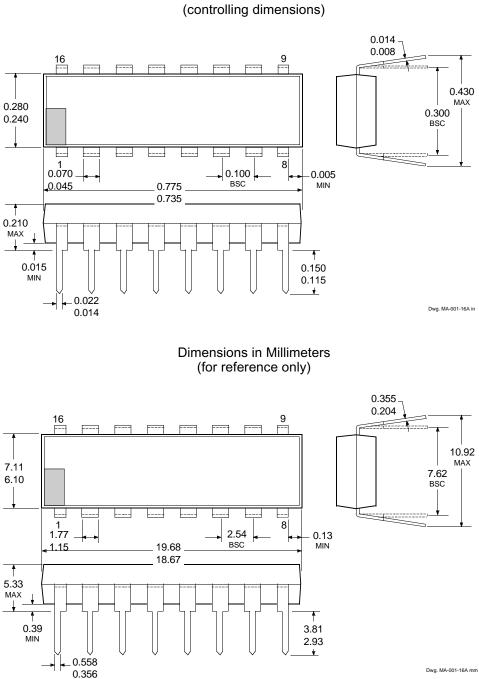
Blue	3.0 - 4.0 V
Green	1.8 - 2.2 V
Yellow	2.0 - 2.1 V
Amber	1.9 – 2.65 V
Red	1.6 – 2.25 V
Infrared	1.2 – 1.5 V

Pattern Layout. This device has a common logicground and power-ground terminal. If ground pattern layout contains large common-mode resistance, and the voltage between the system ground and the LATCH ENABLE or CLOCK terminals exceeds 2.5 V (because of switching noise), these devices may not operate correctly.



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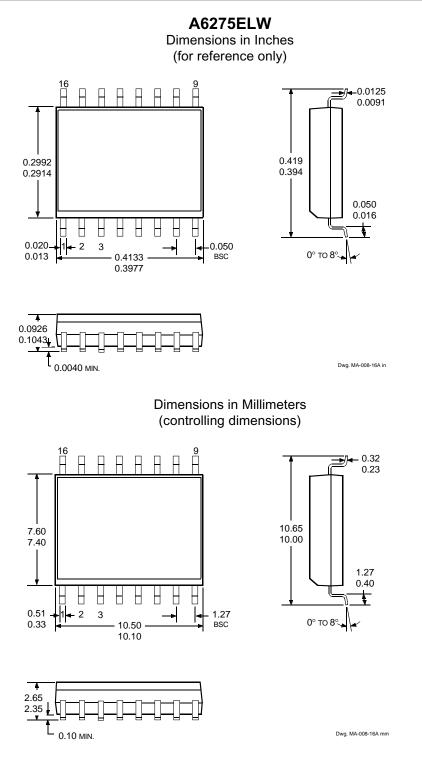
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A6275EA Dimensions in Inches

NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.

- 2. Lead spacing tolerance is non-cumulative
- 3. Lead thickness is measured at seating plane or below.
- 4. Supplied in standard sticks/tubes of 25 devices.



NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.

- 2. Lead spacing tolerance is non-cumulative.
 - 3. Supplied in standard sticks/tubes of 47 devices or add "TR" to part number for tape and reel.



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